

Attorney Docket No.: 09792909.4970
Customer No.: 26263

**AMENDMENT UNDER 37 CFR §1.116
EXPEDITED PROCEDURE
GROUP 2811
PATENT APPLICATION**



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:

Tsutomu TANAKA, et al.

Group Art Unit: 2811

Application No.: 09/827,676

Examiner: Quang D. Vu

Confirmation No.: 6747

Filed: April 6, 2001

For: THIN-FILM TRANSISTOR AND METHOD FOR MAKING THE SAME

AMENDMENT UNDER 37 C.F.R. § 1.116

ATTN: BOX AF

Commissioner Of Patents and Trademarks
Washington, D.C. 20231

Sir:

In response to the Final Office Action dated November 5, 2002, Paper No. 9, please amend the above-identified application as follows:

IN THE CLAIMS:

Please cancel Claim 14 without prejudice or disclaimer.

Please enter the following amended claim:

4. (Twice Amended) A method of making a bottom-gate thin-film transistor comprising:
- forming a gate electrode on a substrate;
- forming a gate insulating film on the gate electrode;

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#12/ Amended
N/E
Amended
8/12/03

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